NSN 5961-01-305-7479

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Inclosure	Material:
meiosure	material.

Metal

Overall Length:

0.150 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.230 inches

Internal Configuration:

Field effect

Electrode Internally-electrically Connected To Case:

Drain

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Electrostatic sensitive

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 drain to gate voltage and 60.0 drain to source voltage and 15.0 gate to source voltage

Current Rating Per Characteristic:

400.00 milliamperes source cutoff current minor

Special Features:

N-channel mosfet

Test Data Document:

80063-a3012708 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0